

Features

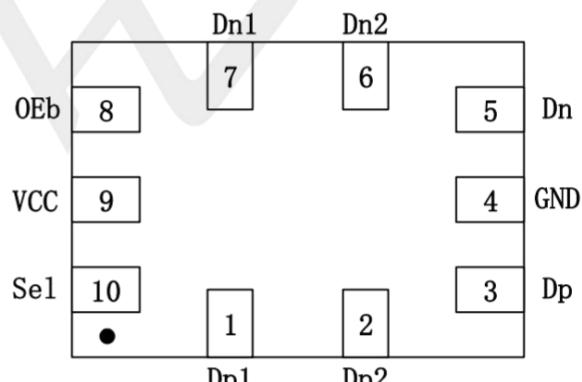
- Low On-resistance, $R_{on}=1.5\Omega$ when VCC =5V
- 1.8V Logic Compatible Control Pin
- High Off-Isolation: -100dB @ 100KHz
- COM+/- Overrides VCC to Achieve True Isolation Even When Supply Is Dead
- Low Channel-to-Channel Crosstalk: -97dB @ 100KHz
- High Bandwidth (-3dB @800MHz) Suitable For USB2.0 High-Speed Routing
- Low Quiescent Current (<2uA) With Very Wide Supply Range (1.5V ~ 5.5V)

Applications

- Mobile Phones, Tablets and Notebooks
- Anywhere a USB Type-C™ or Micro-B Connector is Used

PIN CONFIGURATIONS (TOP VIEW)

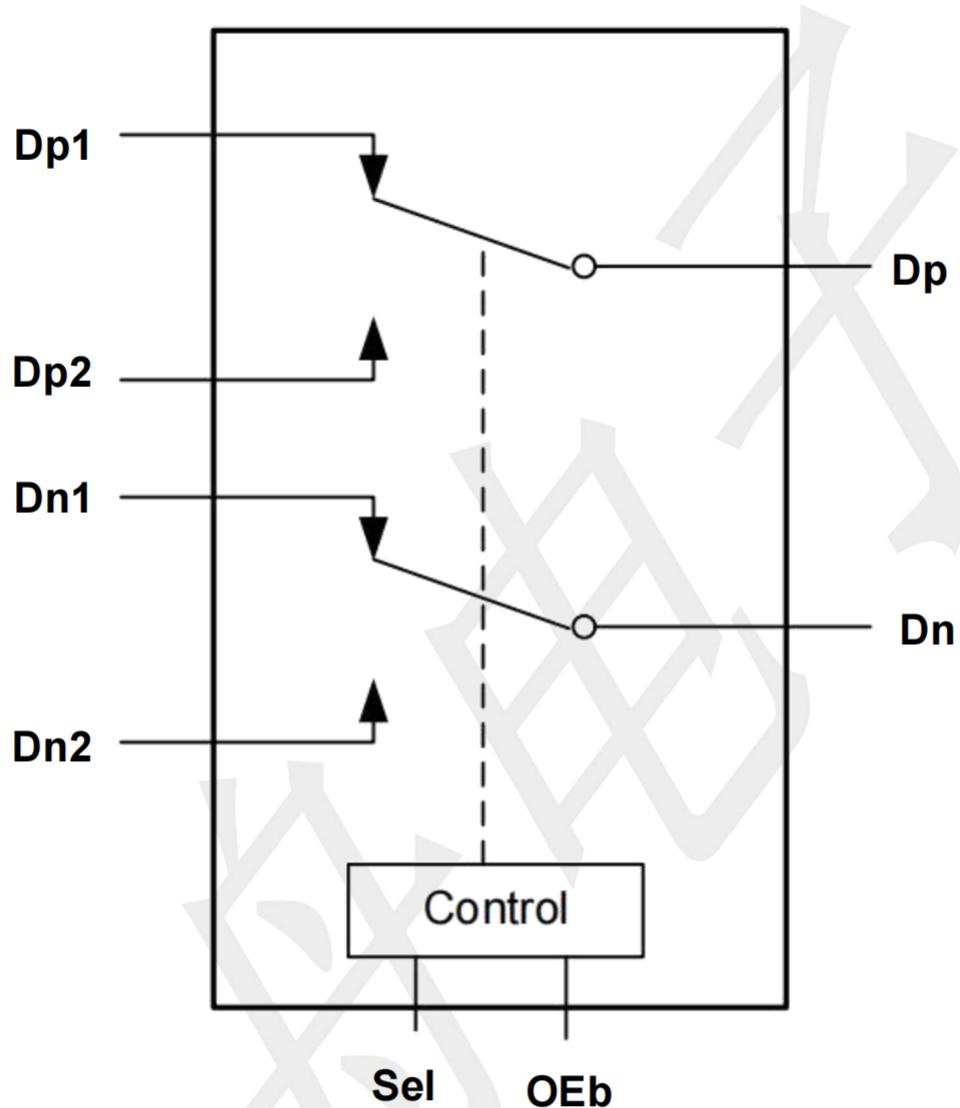
QFN1418-10L



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	Dp1	Analog/Digital Signal Ports (Normally closed)
2	Dp2	Analog/Digital Signal Ports (Normally open)
3	Dp	Port A common data terminal, Connect to Dp1 or Dp2 according to Sel logic
4	GND	Ground
5	Dn	Port B common data terminal, Connect to NC2 or NO2 according to SEL logic
6	Dn2	Analog/Digital Signal Ports (Normally open)
7	Dn1	Analog/Digital Signal Ports (Normally closed)
8	OEb	output enable input (active LOW), prohibit high level connection
9	VCC	Supply voltage
10	Sel	Logic Input Selection

BLOCK DIAGRAM



Function Table

OEb	Input Sel	Function
0	0	Dp=Dp1 and Dn=Dn1
0	1	Dp=Dp2 and Dn=Dn2

Switches Shown For Logic "0" Input, /OE is prohibited from connecting to high level 1 in application.

Absolute Maximum Ratings

(Unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	VCC	-0.3 ~ +6.5	V
Input Voltage	VIN	-0.3 ~ +6.5	V
OEb Input Voltage	VOEb	-0.3 ~ +0	V
Continuous Current Through Dp, Dn		±100	mA
Peak Current Through Dp, Dn (pulsed at 1ms 50% duty cycle)		±200	mA
Storage Temperature Range	TSTG	-55 ~ +150	°C
Operating Junction Temperature	TJ	150	°C
Lead Temperature (Soldering, 10 seconds)	TL	260	°C
Power Dissipation	PD	250	mW

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommend operating ratings

(Unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage Operating	VCC	1.5 ~ 5.5	V
Control Input Voltage	VIN	-0.3 ~ 5.5	V
Input Signal Voltage	VD	-0.3 ~ 5.5	V
Operating Temperature	TA	-40 ~ +85	°C
Junction to Ambient	RθJA	360	°C/W

DC Electrical Characteristics (TA =25°C, VC=+3.3V,unless otherwise specified)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
High-Level Input Voltage	VIH	VCC=3.3V ~ 5.5V	1.6	--	--	V
		VCC=1.5V ~ 3.3V	1.4	--	--	V
Low-Level Input Voltage	VIL	VCC=3.3V ~ 5.5V	--	--	0.6	V
		VCC=1.5V ~ 3.3V	--	--	0.4	V
Supply quiescent current	I _{CC}	I _A =0, V _{SEL} =0 or V _{SEL} =VCC	--	--	1.0	uA
Increase in ICC per input	I _{CCIT}	I _A =0, VCC=4.5V V _{SEL} >1.8 or V _{SEL} <0.5	--	--	1.0	uA
Off state leakage from Dn or Dp to Dnx (or Dpx)	I _{COMx}	V _{COM} = 5.5V , V _{NC} (or NO) = 0V	--	--	±2.0	uA
On-Resistance	R _{ON1}	V _A =0 ~ 0.5V, I _A =30mA	--	3.6	3.9	Ω
	R _{ON2}	V _A =0.5 ~ 2.0V, I _A =30mA	--	3.0	3.5	Ω
	R _{ON3}	V _A =2.0 ~ 4.0V, I _A =30mA	--	2.5	3.5	Ω
	R _{ON4}	V _A =4.0 ~ 5.5V, I _A =30mA	--	1.5	1.8	Ω
On-Resistance Flatness	R _{FLAT1}	V _A =0 ~ 0.5V, I _A =30mA	--	1.6	--	Ω
	R _{FLAT2}	V _A =0.5 ~ 2.0V, I _A =30mA	--	0.7	--	Ω
	R _{FLAT3}	V _A =2.0 ~ 4.0V, I _A =30mA	--	0.5	--	Ω
	R _{FLAT4}	V _A =4.0 ~ 5.5V, I _A =30mA	--	0.3	--	Ω
On-Resistance Matching Between Channels	Δ R _{ON}	V _A =0~5.5V, I _A =30mA	--	0.1	0.2	Ω

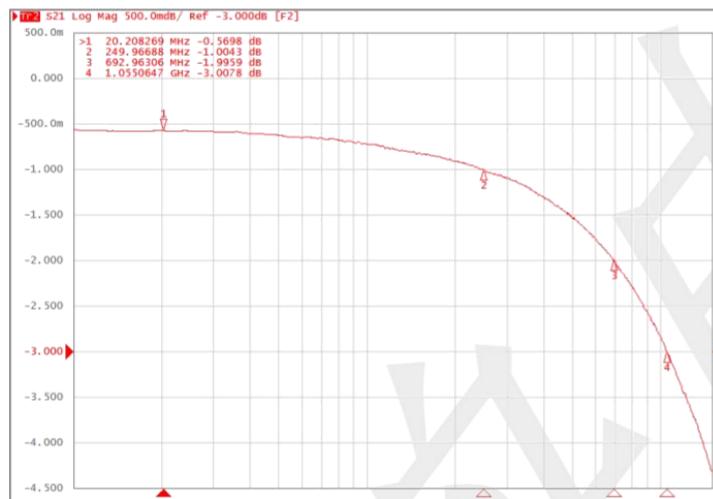
AC Electronics Characteristics (Ta=25°C, VCC=+3.3V, unless otherwise noted)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
Turn-On Time	T _{ON}	V _A =1.5V, C _L =35pF, R _L =50Ω	--	200	--	ns
Turn-Off Time	T _{OFF}	V _A =1.5V, C _L =35pF, R _L =50Ω	--	200	--	ns
Break-Before-Make time	T _{BBA}	V _A =1.5V, C _L =35pF, R _L =50Ω	--	500	--	ns
-3dB Bandwidth	BW	R _L =50Ω, C _L =5pF	--	550	--	MHz
		R _L =50Ω, C _L =0pF	--	800	--	MHz
Off isolation	OIRR	F=1KHz, R _L =50Ω	--	-81	--	dB
		F=10KHz, R _L =50Ω	--	-80	--	dB
Crosstalk	Xtalk	F=1KHz, R _L =50Ω	--	-83	--	dB
		F=10KHz, R _L =50Ω	--	-82	--	dB
Total Harmonic Distortion	THD	F=20Hz to 20KHz V _A =600mVp-p @R _L =32Ω	--	-80	--	dB

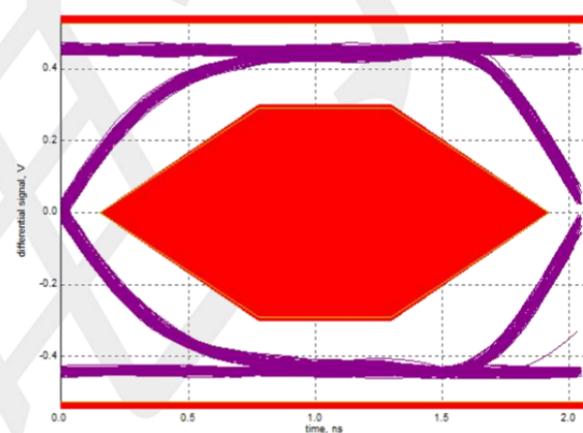
Capacitance (Ta=25°C, VCC=+3.3V, unless otherwise noted)

PARAMETER	SYMBOL	TEST Conditions	MIN	TYP	MAX	UNIT
Off capacitance	C _{OFF}	F=100KHz,	--	5.0	--	pF
On capacitance	C _{ON}	F=100KHz,	--	7.0	--	pF

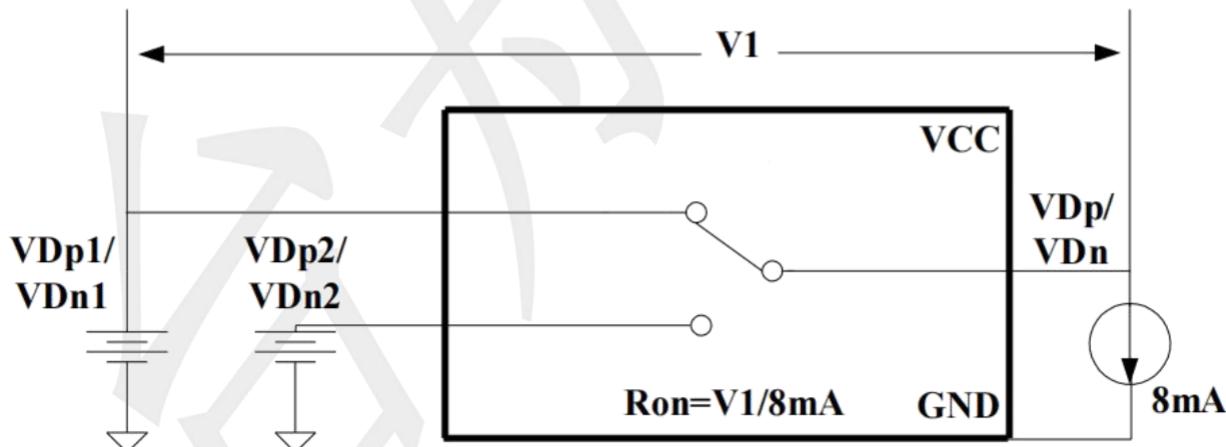
Typical Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)



Bandwidth

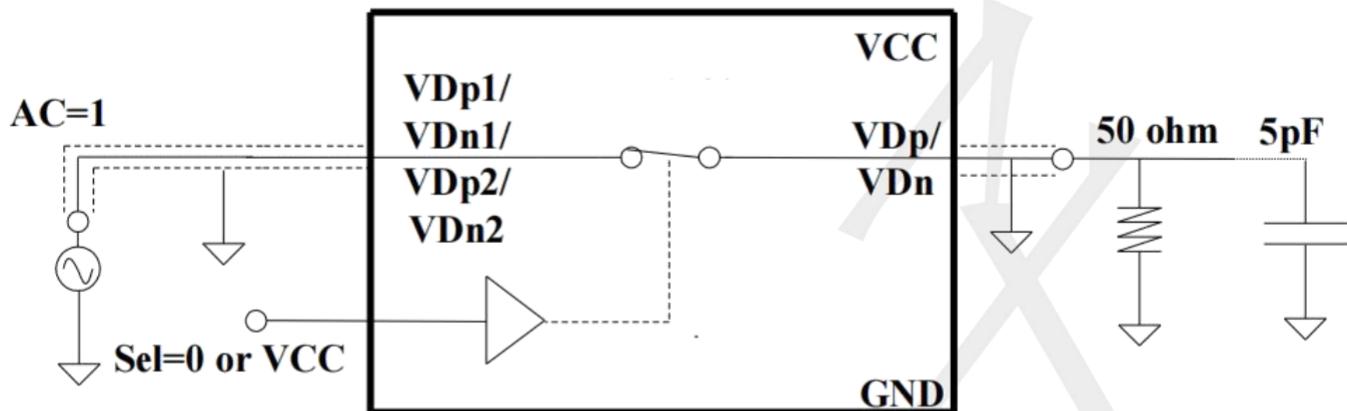


Eye Diagram (480Mbps)

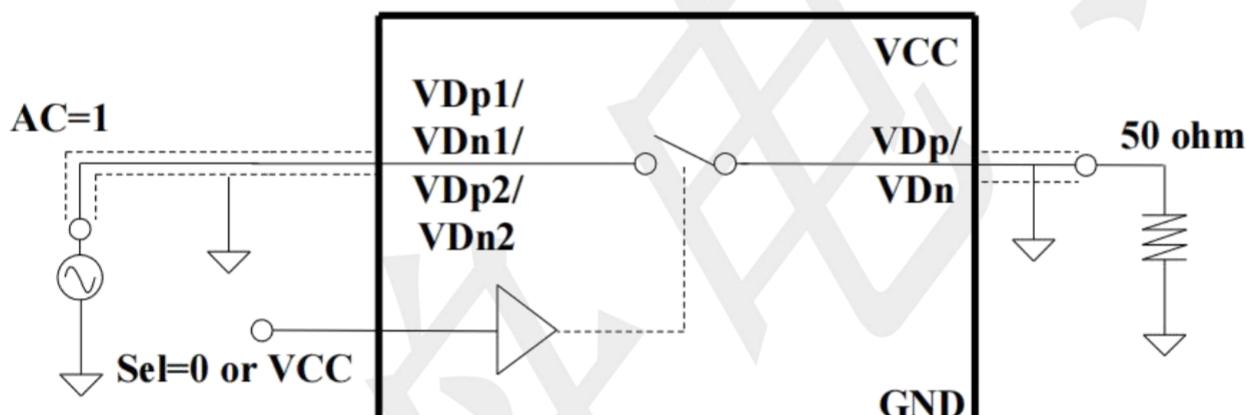


Test Circuit for On Resistor

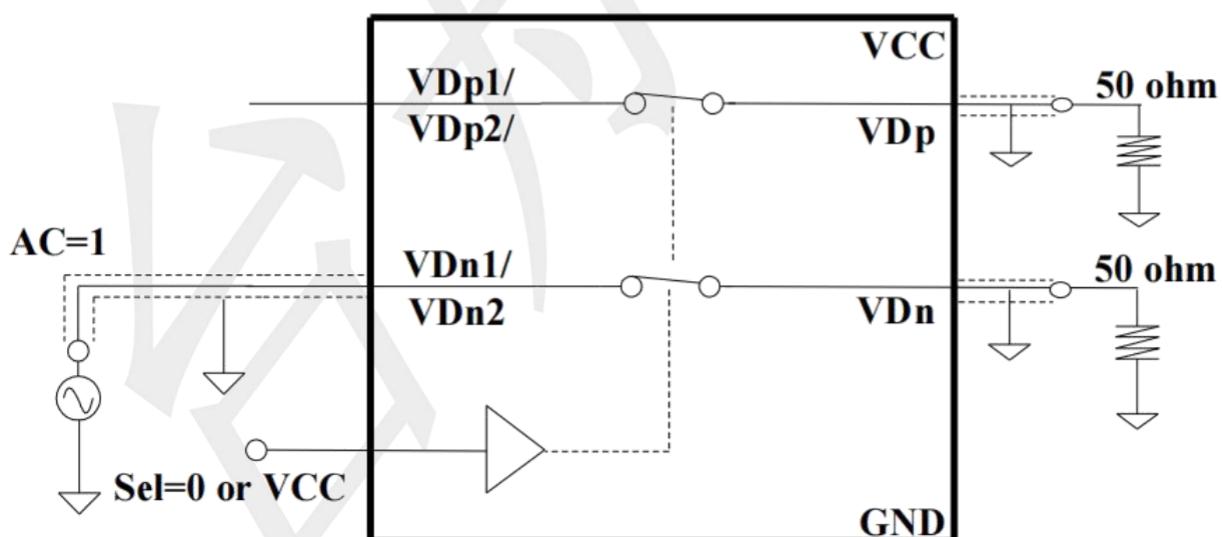
Typical Characteristics (Ta=25°C, unless otherwise noted)



Test Circuit for Bandwidth



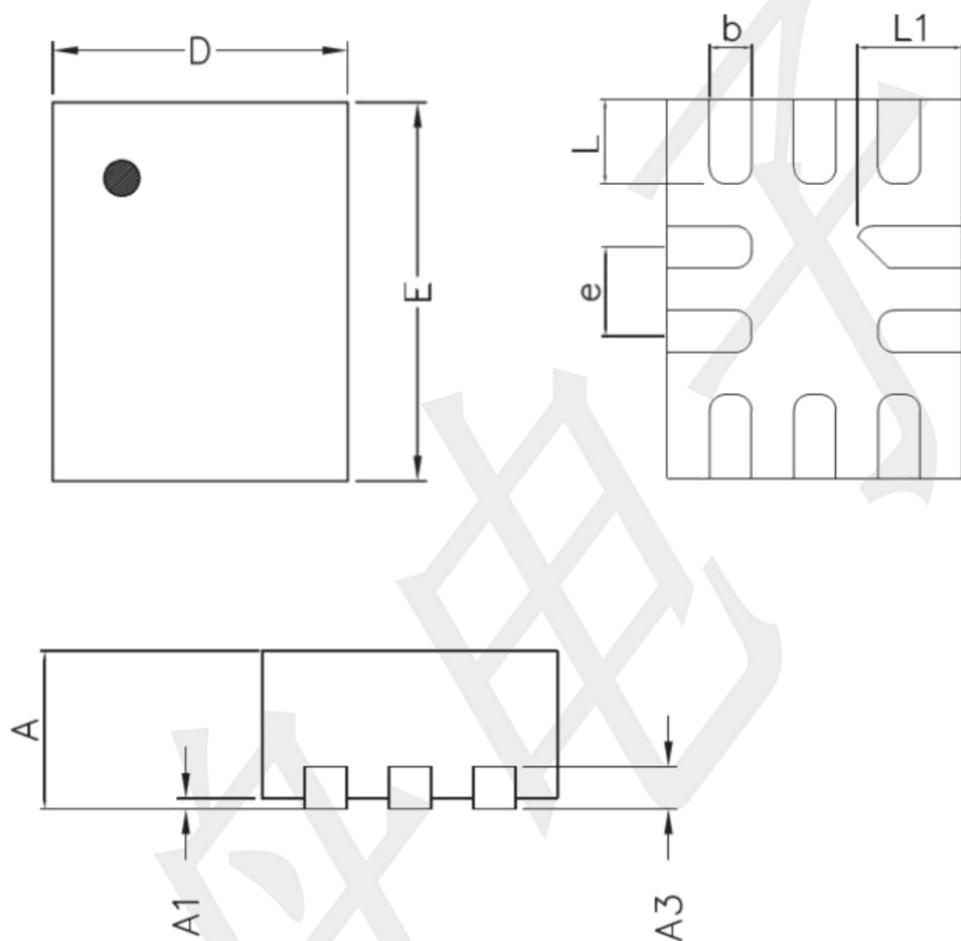
Test Circuit for Off Isolation



Test Circuit for Crosstalk

Package information

QFN1418-10L (Unit: mm)



Symbol	Dimension in Millimeters	
	Min.	Max.
A	0.450	0.550
A1	0.000	0.050
A3	0.152 Ref.	
D	1.350	1.450
E	1.750	1.850
b	0.150	0.250
e	0.400 Typ.	
L	0.350	0.450
L1	0.450	0.550